

Features

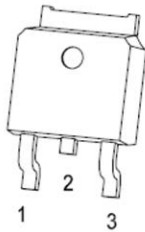
- $V_{DS} = -60V, I_D = -13A$
- $R_{DS(ON)} 100m\Omega @ V_{GS} = -10V (Typ)$
- $R_{DS(ON)} 110m\Omega @ V_{GS} = -4.5V (Typ)$

Application

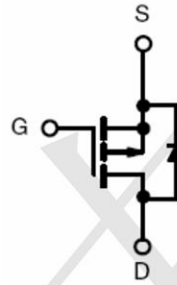
- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

Package and Pin Configuration

TO-252



1. GATE
2. DRAIN
3. SOURCE



Marking:



Absolute Maximum Ratings ($T_A = 25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|---|--------------------|------------|---------------|
| Drain-Source Voltage | V_{DS} | -60 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Drain Current-Continuous | I_D | -13 | A |
| Drain Current-Continuous($T_C = 100^\circ C$) | $I_D(100^\circ C)$ | -8.5 | A |
| Pulsed Drain Current | I_{DM} | -30 | A |
| Maximum Power Dissipation | P_D | 60 | W |
| Derating factor | | 0.4 | W/ $^\circ C$ |
| Single pulse avalanche energy ^(Note 5) | E_{AS} | 50 | mJ |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55 To 175 | $^\circ C$ |

Thermal Characteristic

| | | | |
|--|-----------------|-----|--------------|
| Thermal Resistance, Junction-to-Case ^(Note 2) | $R_{\theta JC}$ | 2.5 | $^\circ C/W$ |
|--|-----------------|-----|--------------|

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|---|--------------|--|-----|--------|-----------|------------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=-250\mu A$ | -60 | - | - | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=-60V, V_{GS}=0V$ | - | - | -1 | μA |
| Gate-Body Leakage Current | I_{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | - | - | ± 100 | nA |
| On Characteristics (Note 3) | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=-250\mu A$ | 2.0 | 3.0 | 4.0 | V |
| Drain-Source On-State Resistance | $R_{DS(ON)}$ | $V_{GS}=-10V, I_D=-12A$ | - | 100 | 110 | m Ω |
| | | $V_{GS}=-4.5V, I_D=-8A$ | - | 110 | 140 | Ω |
| Forward Transconductance | g_{FS} | $V_{DS}=-5V, I_D=-12A$ | - | 10 | - | S |
| Dynamic Characteristics (Note 4) | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS}=-30V, V_{GS}=0V,$ $F=1.0MHz$ | - | 1630.7 | - | PF |
| Output Capacitance | C_{oss} | | - | 90.6 | - | PF |
| Reverse Transfer Capacitance | C_{rss} | | - | 77.3 | - | PF |
| Switching Characteristics (Note 4) | | | | | | |
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD}=-30V, R_L=1.5\Omega,$ $V_{GS}=-10V, R_G=3\Omega$ | - | 11 | - | nS |
| Turn-on Rise Time | t_r | | - | 14 | - | nS |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 33 | - | nS |
| Turn-Off Fall Time | t_f | | - | 13 | - | nS |
| Total Gate Charge | Q_g | $V_{DS}=-30, I_D=-13A,$ $V_{GS}=-10V$ | - | 37.6 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 4.3 | - | nC |
| Gate-Drain Charge | Q_{gd} | | - | 7.2 | - | nC |
| Drain-Source Diode Characteristics | | | | | | |
| Diode Forward Voltage | V_{SD} | $V_{GS}=0V, I_S=-12A$ | - | - | -1.2 | V |
| Diode Forward Current | I_S | | - | - | -12 | A |
| Reverse Recovery Time | t_{rr} | $T_J = 25^\circ\text{C}, I_F = -12A$ $di/dt = -100A/\mu s$ (Note 3) | - | 35 | - | nS |
| Reverse Recovery Charge | Q_{rr} | | - | 38 | - | nC |
| Forward Turn-On Time | t_{on} | Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD) | | | | |

Typical Characteristics

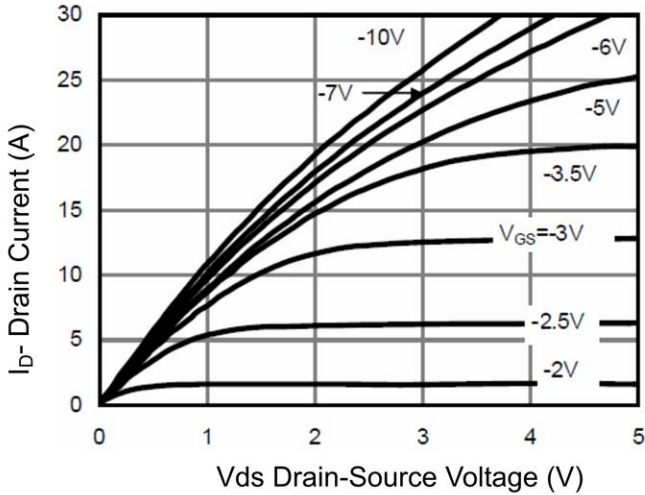


Figure 1 Output Characteristics

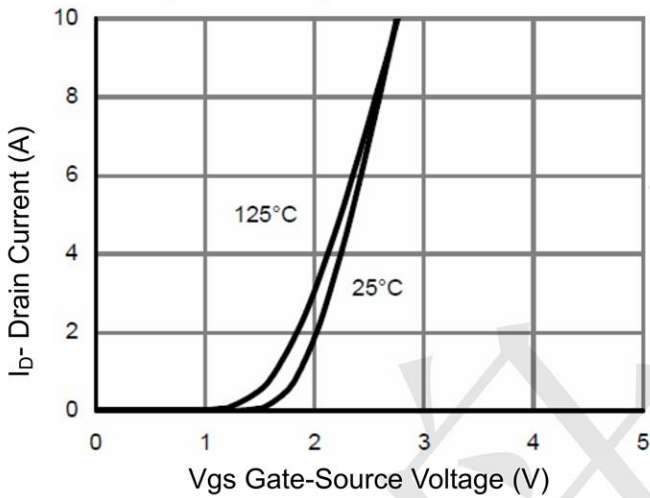


Figure 2 Transfer Characteristics

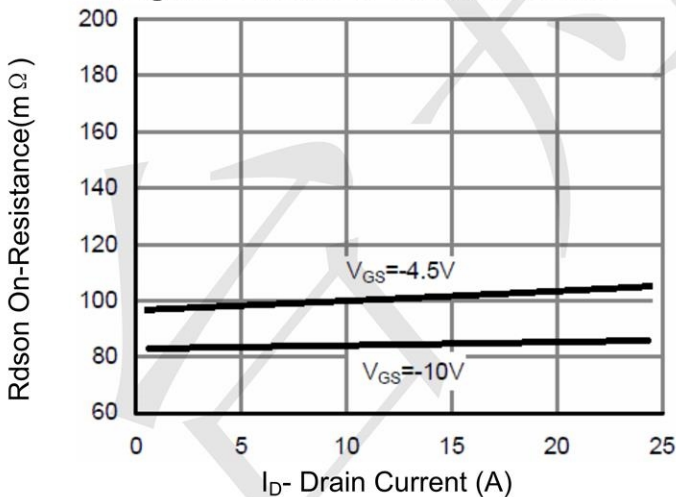


Figure 3 $R_{ds(on)}$ - Drain Current

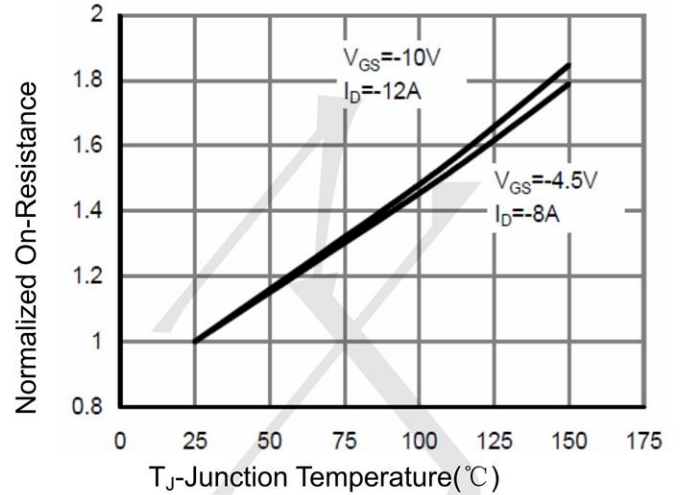


Figure 4 $R_{ds(on)}$ -Junction Temperature

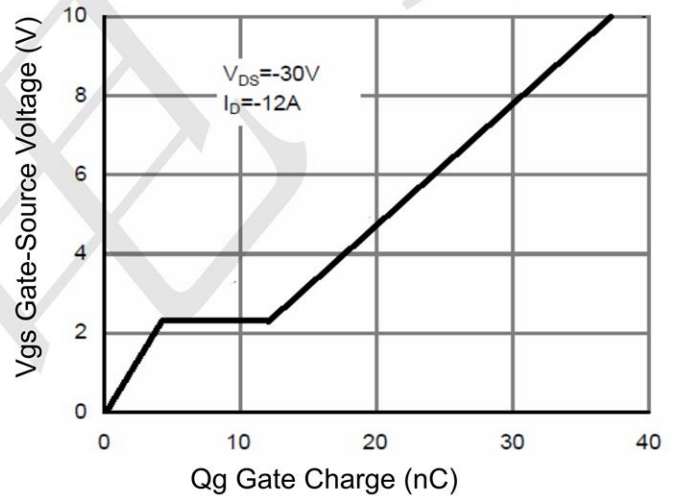


Figure 5 Gate Charge

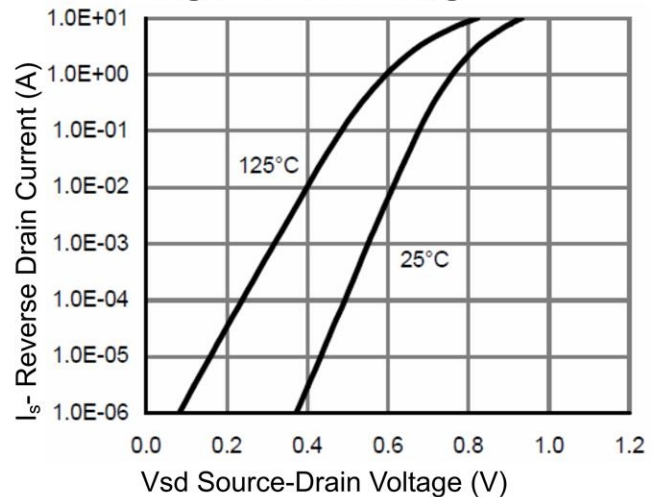


Figure 6 Source- Drain Diode Forward

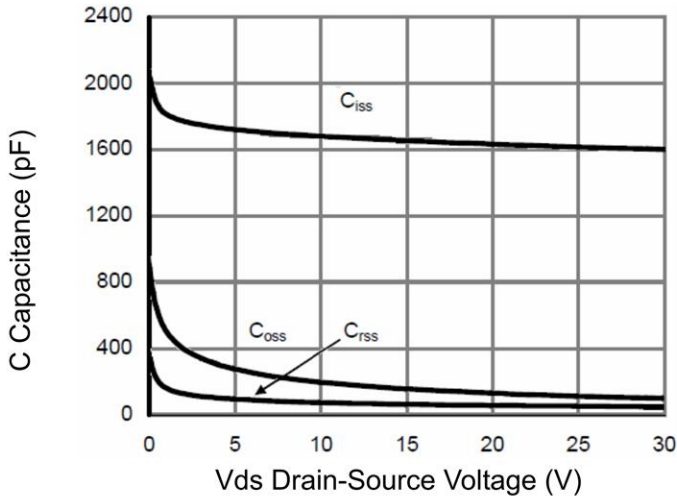


Figure 7 Capacitance vs Vds

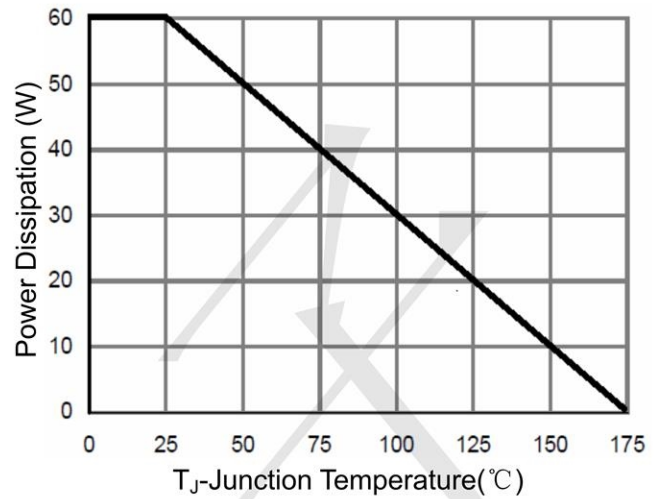


Figure 9 Power De-rating

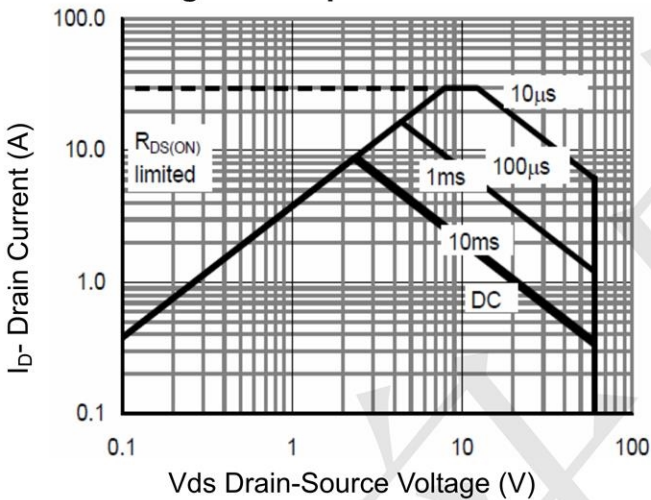


Figure 8 Safe Operation Area

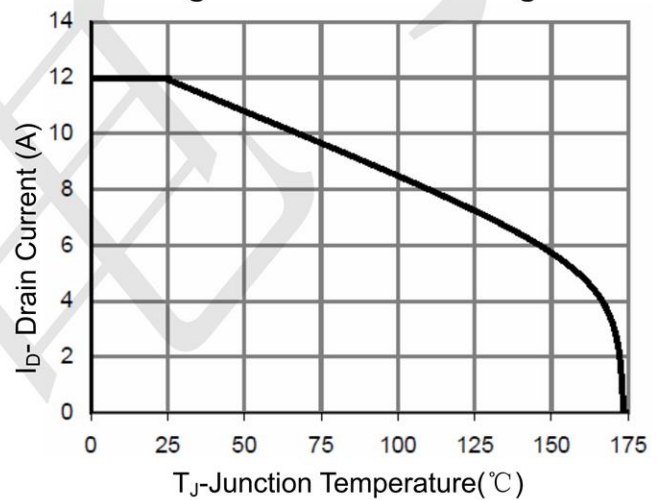


Figure 10 ID Current De-rating

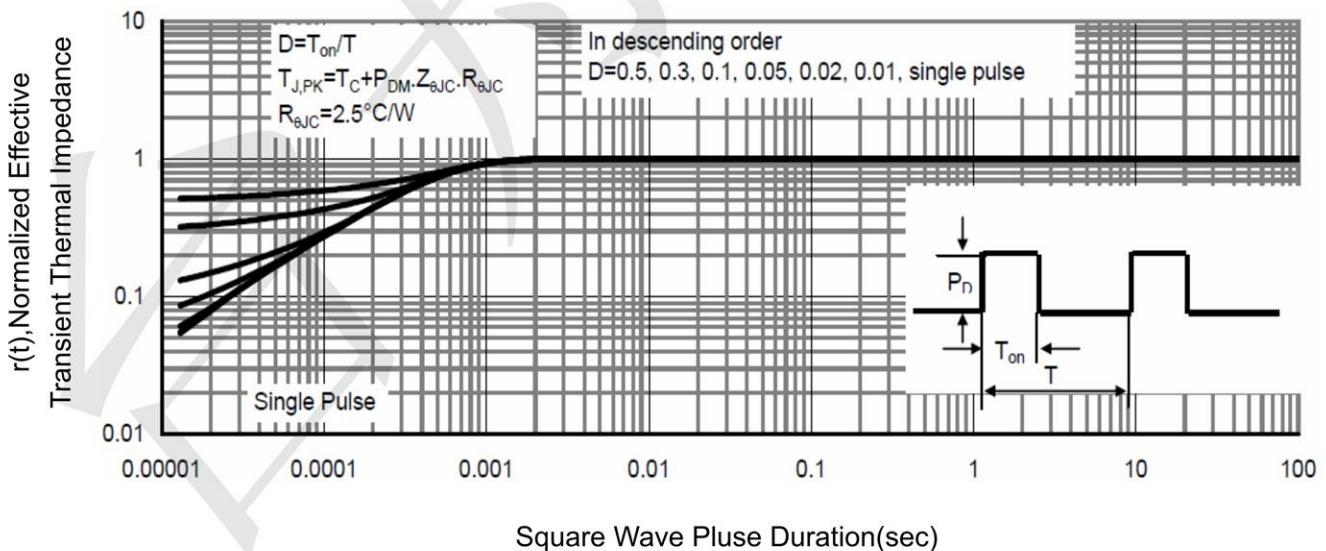
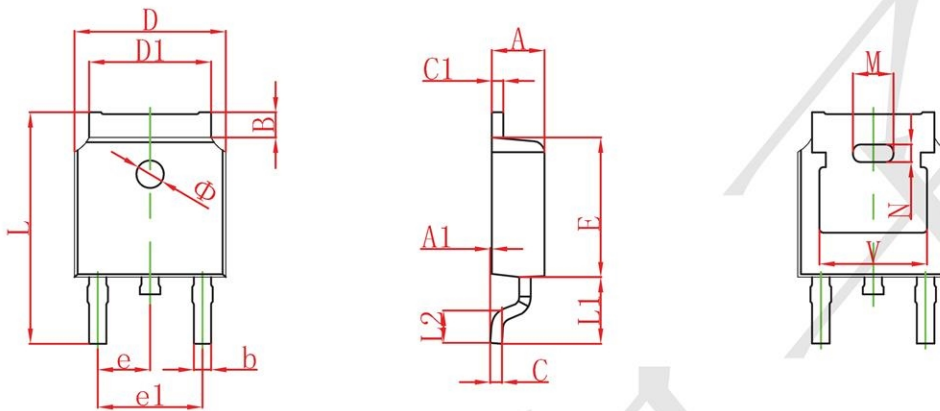


Figure 11 Normalized Maximum Transient Thermal Impedance

TO252 Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|--------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 2.200 | 2.380 | 0.087 | 0.094 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| B | 0.800 | 1.400 | 0.031 | 0.055 |
| b | 0.710 | 0.810 | 0.028 | 0.032 |
| c | 0.460 | 0.560 | 0.018 | 0.022 |
| c1 | 0.460 | 0.560 | 0.018 | 0.022 |
| D | 6.500 | 6.700 | 0.256 | 0.264 |
| D1 | 5.130 | 5.460 | 0.202 | 0.215 |
| E | 6.000 | 6.200 | 0.236 | 0.244 |
| e | 2.286 TYP. | | 0.090 TYP. | |
| e1 | 4.327 | 4.727 | 0.170 | 0.186 |
| M | 1.778REF. | | 0.070REF. | |
| N | 0.762REF. | | 0.018REF. | |
| L | 9.800 | 10.400 | 0.386 | 0.409 |
| L1 | 2.9REF. | | 0.114REF. | |
| L2 | 1.400 | 1.700 | 0.055 | 0.067 |
| V | 4.830 REF. | | 0.190 REF. | |
| Φ | 1.100 | 1.300 | 0.043 | 0.051 |